



## Electrical Characteristics : $T_c=25^\circ\text{C}$ , unless otherwise noted

Parameter	Symbol	Test condition	Min	Typ	Max	Units
<b>OFF</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}} = 0 \text{ V}, I_{\text{D}} = 250 \mu\text{A}$	200	--	--	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}} = 200 \text{ V}, V_{\text{GS}} = 0 \text{ V}$	--	--	1	$\mu\text{A}$
		$V_{\text{DS}} = 160 \text{ V}, T_c = 125^\circ\text{C}$	--	--	10	$\mu\text{A}$
Forward Gate-Source Leakage Current	$I_{\text{GSSF}}$	$V_{\text{GS}} = 30 \text{ V}, V_{\text{DS}} = 0 \text{ V}$	--	--	100	$\mu\text{A}$
Reverse Gate-Source Leakage Current	$I_{\text{GSSR}}$	$V_{\text{GS}} = -30 \text{ V}, V_{\text{DS}} = 0 \text{ V}$	--	--	-100	$\mu\text{A}$
<b>ON</b>						
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = 250 \mu\text{A}$	3	--	5	V
Drain-Source On-Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}} = 10 \text{ V}, I_{\text{D}} = 9 \text{ A}$	--	0.14	0.17	$\Omega$
Forward Transconductance <sup>(Note 4)</sup>	$g_{\text{FS}}$	$V_{\text{DS}} = 30 \text{ V}, I_{\text{D}} = 9 \text{ A}$	--	6	--	S
<b>DYNAMIC</b>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}} = 25 \text{ V}, V_{\text{GS}} = 0 \text{ V}, f = 1.0 \text{ MHz}$	--	950	--	pF
Output Capacitance	$C_{\text{oss}}$		--	180	--	pF
Reverse Transfer Capacitance	$C_{\text{rss}}$		--	20	--	pF
<b>SWITCHING</b>						
Turn-On Delay Time <sup>(Note 4,5)</sup>	$t_{\text{d(on)}}$	$V_{\text{DD}} = 100 \text{ V}, I_{\text{D}} = 18 \text{ A}, R_{\text{G}} = 25$	--	26	--	ns
Turn-On Rise Time <sup>(Note 4,5)</sup>	$t_r$		--	30	--	ns
Turn-Off Delay Time <sup>(Note 4,5)</sup>	$t_{\text{d(off)}}$		--	54	--	ns
Turn-Off Fall Time <sup>(Note 4,5)</sup>	$t_f$		--	17	--	ns
Total Gate Charge <sup>(Note 4,5)</sup>	$Q_g$	$V_{\text{DS}} = 160 \text{ V}, I_{\text{D}} = 18 \text{ A}, V_{\text{GS}} = 10 \text{ V}$	--	18	--	nC
Gate-Source Charge <sup>(Note 4,5)</sup>	$Q_{\text{gs}}$		--	4.2	--	nC
Gate-Drain Charge <sup>(Note 4,5)</sup>	$Q_{\text{gd}}$		--	8.2	--	nC
<b>SOURCE DRAIN DIODE</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	----	--	--	18	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{\text{SM}}$	----	--	--	72	A
Drain-Source Diode Forward Voltage	$V_{\text{SD}}$	$V_{\text{GS}} = 0 \text{ V}, I_S = 18 \text{ A}$	--	--	1.5	V
Reverse Recovery Time <sup>(Note 4)</sup>	$t_{\text{rr}}$	$V_{\text{GS}} = 0 \text{ V}, I_S = 18 \text{ A}$ $dI_F / dt = 100 \text{ A}/\mu\text{s}$	--	150	--	ns
Reverse Recovery Charge <sup>(Note 4)</sup>	$Q_{\text{rr}}$		--	0.7	--	$\mu\text{C}$

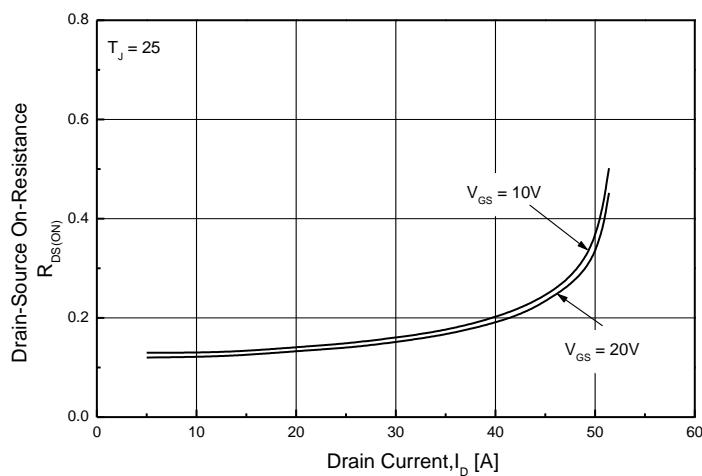
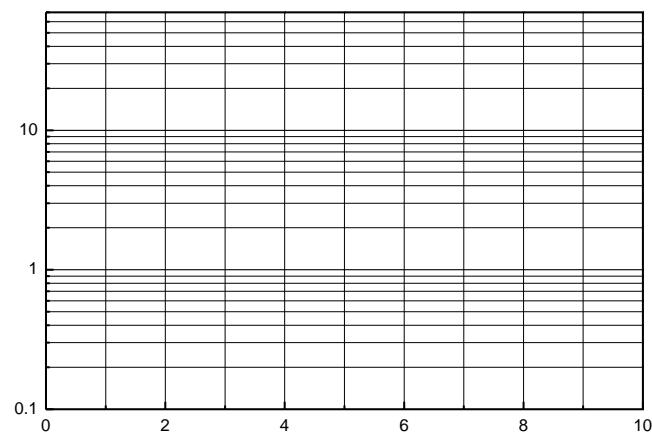
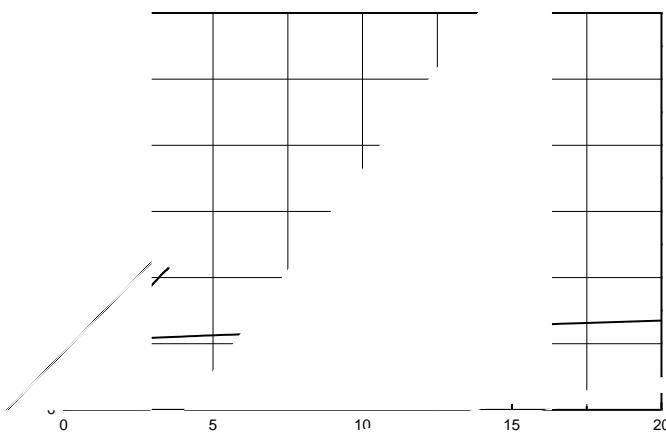
Note :

1. Repeated rating : Pulse width limited by safe operating area

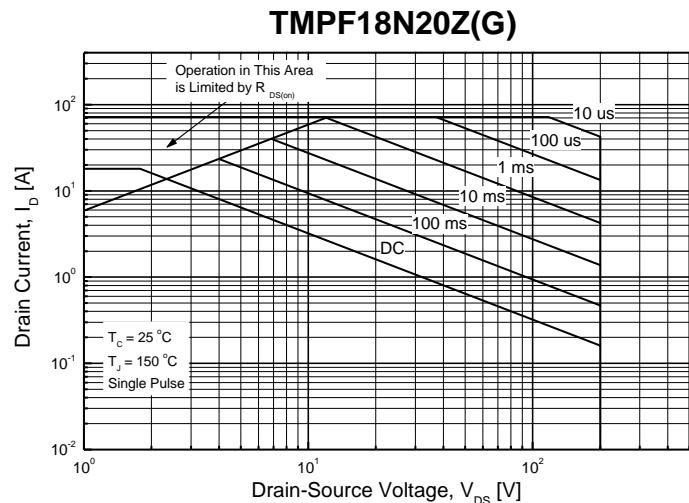
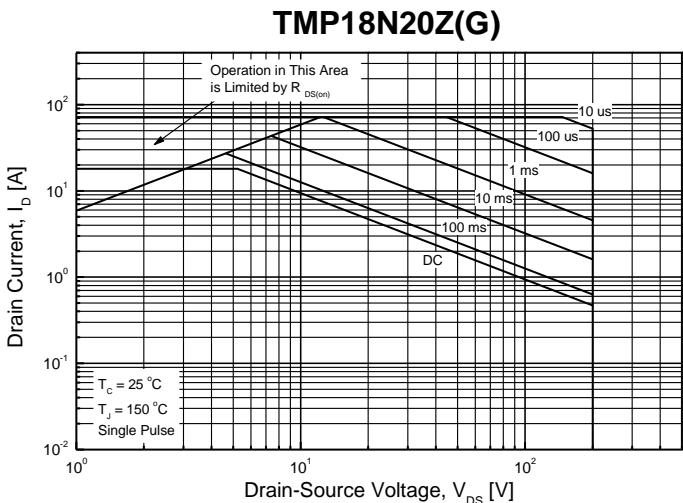
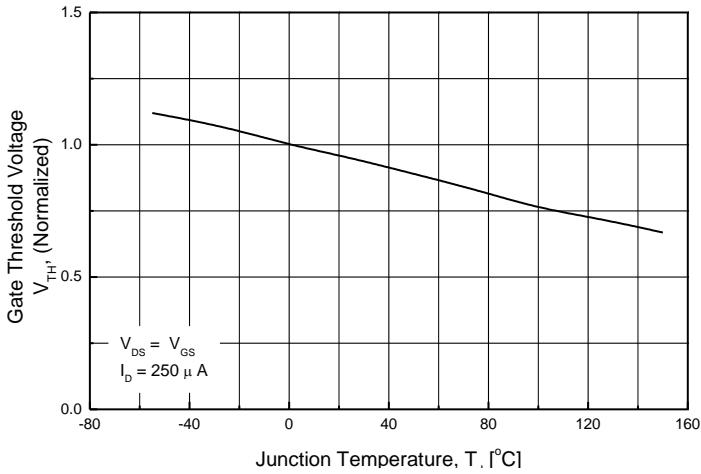
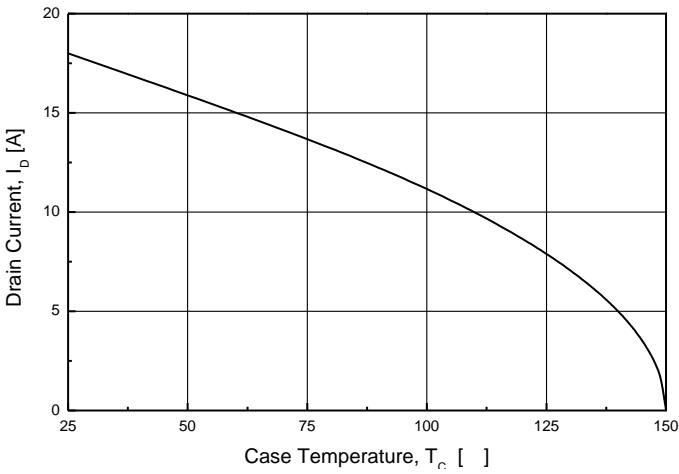
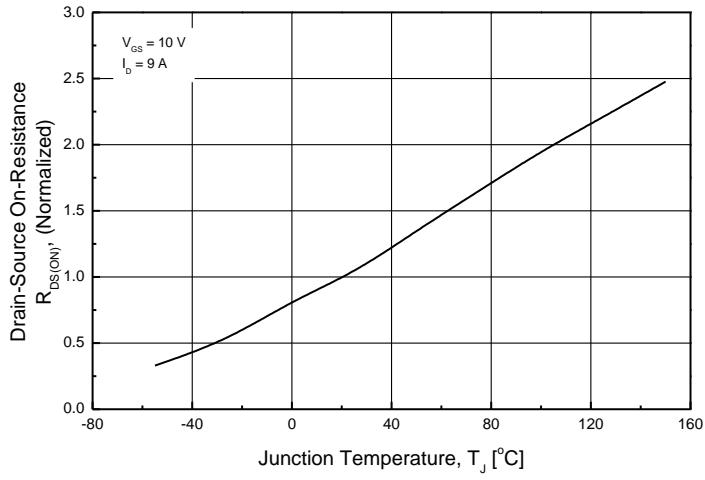
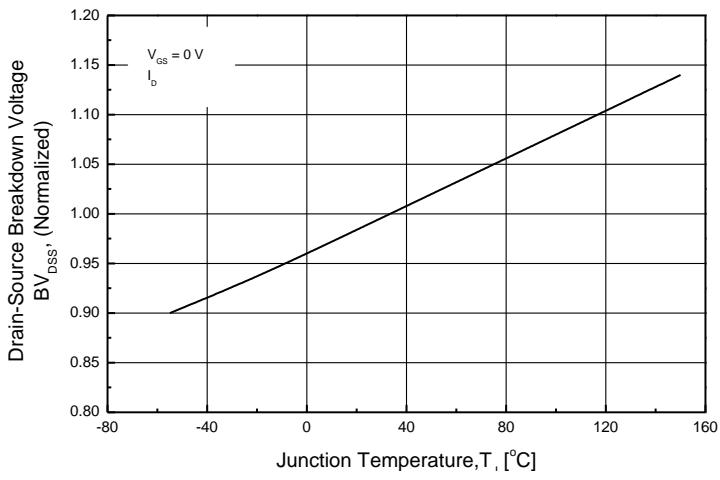
2. L=1.76mH,  $I_{\text{AS}} = 18 \text{ A}$ ,  $V_{\text{DD}} = 50 \text{ V}$ ,  $R_{\text{G}} = 25 \Omega$ , Starting  $T_j = 25^\circ\text{C}$

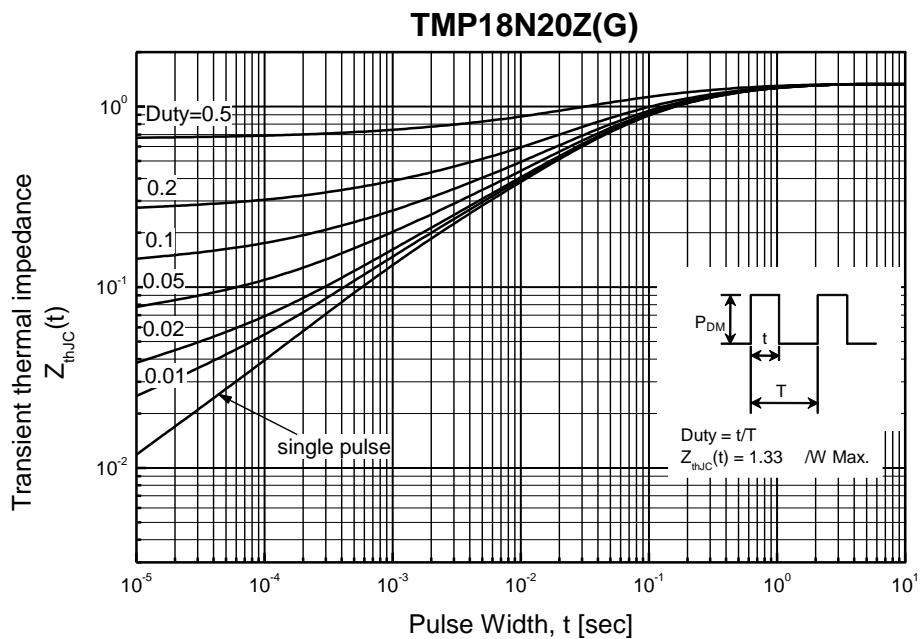
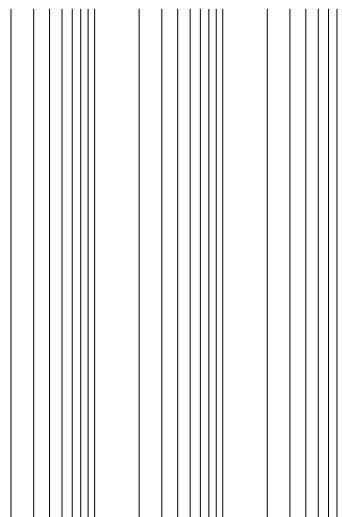
3.  $I_{\text{SD}}$ , di/dt  $\mu\text{s}$ ,  $V_{\text{DD}}$   $\text{V}_{\text{DS}}$ , Starting  $T_j = 25^\circ\text{C}$

5. Essentially Independent of Operating Temperature Typical Characteristics

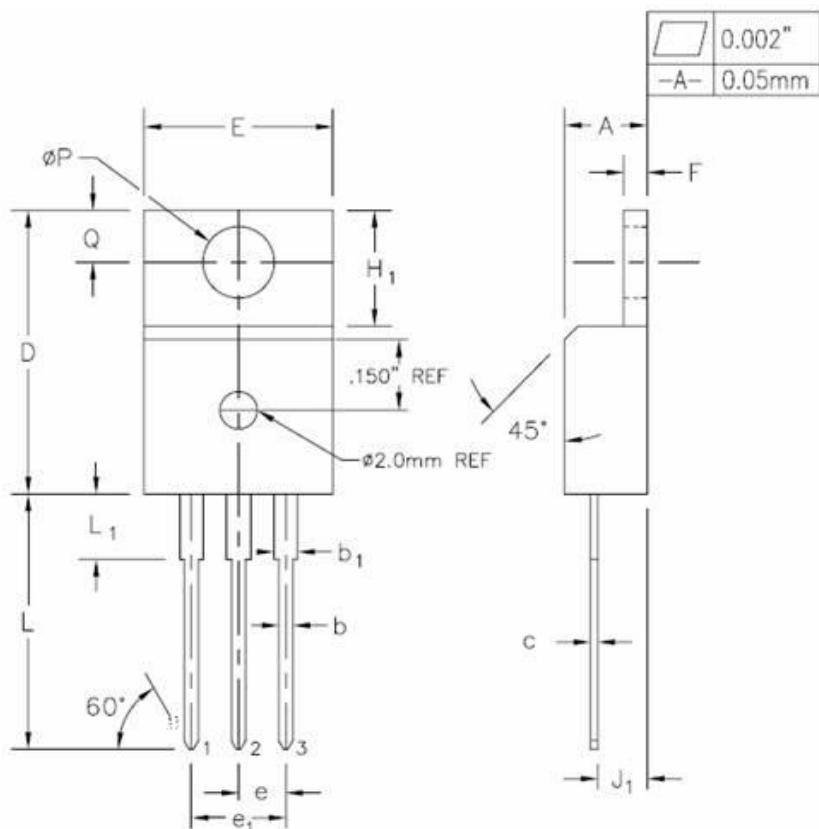


# TMP18N20Z(G)/TMPF18N20Z(G)



**TMPF18N20Z(G)**

## TO-220AB-3L MECHANICAL DATA



SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	0.170	0.180	4.32	4.57	
b <sub>1</sub>	0.028	0.036	0.71	0.91	
b <sub>1</sub>	0.045	0.055	1.15	1.39	
c	0.014	0.021	0.36	0.53	
D	0.590	0.610	14.99	15.49	
E	0.395	0.410	10.04	10.41	
e	0.100	TYP.	2.54	TYP.	
e <sub>1</sub>	0.200	BSC	5.08	BSC	
F <sub>1</sub>	0.048	0.054	1.22	1.37	
H <sub>1</sub>	0.235	0.255	5.97	6.47	
J <sub>1</sub>	0.100	0.110	2.54	2.79	
L	0.530	0.550	13.47	13.97	
L <sub>1</sub>	0.130	0.150	3.31	3.81	
ØP	0.149	0.153	3.79	3.86	
Q	0.102	0.112	2.60	2.84	

## **TO-220F-3L MECHANICAL DATA**

